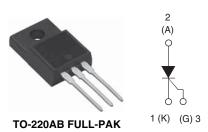


Vishay High Power Products

#### Phase Control SCR TO-220AB FULL-PAK, 16 A



PRODUCT SUMMARY		
V <sub>T</sub> at 10 A	1.4 V	
I <sub>TSM</sub>	200 A	
V <sub>RRM</sub>	800/1200 V	

#### DESCRIPTION/FEATURES

The 16TTS..FPPbF High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology



RoHS\*

used has reliable operation up to 125 °C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

Fully isolated package ( $V_{INS} = 2500 V_{RMS}$ ) is UL E78996 approved **GN** 

This product has been designed and qualified for industrial level and lead (Pb)-free ("PbF" suffix).

OUTPUT CURRENT IN TYPICAL APPLICATIONS				
APPLICATIONS	SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS			
Capacitive input filter $T_A = 55 \text{ °C}$ , $T_J = 125 \text{ °C}$ , common heatsink of 1 °C/W	13.5	17	A	

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	TEST CONDITIONS	VALUES	UNITS		
I <sub>T(AV)</sub>	Sinusoidal waveform	10	•		
I <sub>RMS</sub>		16	- A		
V <sub>DRM</sub> /V <sub>RRM</sub>	Range, for higher voltage up to 1600 V contact factory	800/1200	V		
I <sub>TSM</sub>		200	A		
V <sub>T</sub>	10 A, T <sub>J</sub> = 25 °C	1.4	V		
dV/dt		500	V/µs		
dl/dt		150	A/µs		
TJ	Range	- 40 to 125	°C		

VOLTAGE RATINGS					
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>DRM</sub> , MAXIMUM PEAK DIRECT VOLTAGE V	I <sub>RRM</sub> /I <sub>DRM</sub> AT 125 °C mA		
16TTS08FPPbF	800 800		10		
16TTS12FPPbF	1200	1200	10		

\* Pb containing terminations are not RoHS compliant, exemptions may apply

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ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
PARAMETER	STINDUL	TEST CONDITIONS	TYP. MAX.	
Maximum average on-state current	I <sub>T(AV)</sub>	$T_c = 95 \text{ °C}$ , 180° conduction, half sine wave	10	
Maximum RMS on-state current	I <sub>RMS</sub>		16	А
Maximum peak, one-cycle,	1	10 ms sine pulse, rated V <sub>RRM</sub> applied	170	A
non-repetitive surge current	I <sub>TSM</sub>	10 ms sine pulse, no voltage reapplied	200	
Movimum 12t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	144	A <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing	1-1	10 ms sine pulse, no voltage reapplied	200	A-S
Maximum I <sup>2</sup> √t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	2000	A²√s
Maximum on-state voltage drop	V <sub>TM</sub>	10 A, T <sub>J</sub> = 25 °C	1.4	V
On-state slope resistance	r <sub>t</sub>	<sup>r</sup> t 125 °C		mΩ
Threshold voltage	V <sub>T(TO)</sub>	T <sub>J</sub> = 125 °C	1.1	V
	1 //	$T_J = 25 ^{\circ}C$	0.5	
Maximum reverse and direct leakage current	I <sub>RM</sub> /I <sub>DM</sub>	$T_J = 125 \text{ °C}$ $V_R = \text{Rated } V_{RRM}/V_{DRM}$	10	mA
Holding current	Ι <sub>Η</sub>	Anode supply = 6 V, resistive load, initial I <sub>T</sub> = 1 A 16TTS08FP, 16TTS12FP	- 100	
Maximum latching current	١L	Anode supply = 6 V, resistive load	200	mA
Maximum rate of rise of off-state voltage	dV/dt		500	V/µs
Maximum rate of rise of turned-on current	dl/dt		150	A/µs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P <sub>GM</sub>		8.0	w
Maximum average gate power	P <sub>G(AV)</sub>		2.0	vv
Maximum peak positive gate current	+ I <sub>GM</sub>		1.5	А
Maximum peak negative gate voltage	- V <sub>GM</sub>		10	V
	I <sub>GT</sub>	Anode supply = 6 V, resistive load, $T_J$ = - 10 °C	90	mA
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, $T_J = 25 \ ^{\circ}C$	60	
		Anode supply = 6 V, resistive load, $T_J = 125 \ ^{\circ}C$	35	
	V <sub>GT</sub>	Anode supply = 6 V, resistive load, $T_J$ = - 10 °C	3.0	
Maximum required DC gate voltage to trigger		Anode supply = 6 V, resistive load, $T_J$ = 25 °C	2.0	
volugo to unggol		Anode supply = 6 V, resistive load, $T_J = 125 \ ^{\circ}C$	1.0	v
Maximum DC gate voltage not to trigger	$V_{GD}$	$T = 125 \degree C V$ = Poted value	0.2	
Maximum DC gate current not to trigger	I <sub>GD</sub>	- T <sub>J</sub> = 125 °C, V <sub>DRM</sub> = Rated value		mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t <sub>gt</sub>	$T_J = 25 \ ^{\circ}C$	0.9	
Typical reverse recovery time	t <sub>rr</sub>	T <sub>.1</sub> = 125 °C	4	μs
Typical turn-off time	t <sub>q</sub>	1 = 125 0	110	

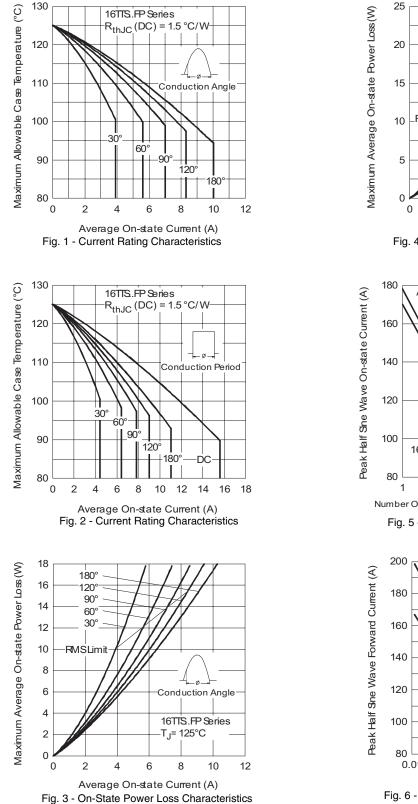


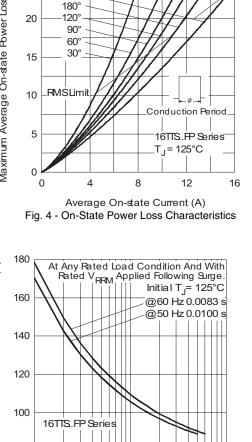
Phase Control SCR Vishay High Power Products TO-220AB FULL-PAK, 16 A

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		- 40 to 125	°C	
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation	1.5		
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		62	°C/W	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	1.5		
Approvimeto weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf · cm	
	maximum			12 (10)	(lbf · in)	
				16TTS	16TTS08FP	
Marking device			Case style TO-220AB FULL-PAK (94/V0)	16TTS	12FP	

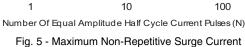
## **Vishay High Power Products**

Phase Control SCR TO-220AB FULL-PAK, 16 A





DC



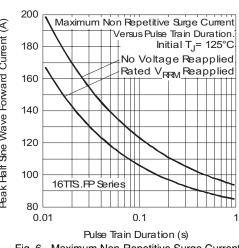


Fig. 6 - Maximum Non-Repetitive Surge Current

100



Phase Control SCR Vishay H TO-220AB FULL-PAK, 16 A

Vishay High Power Products

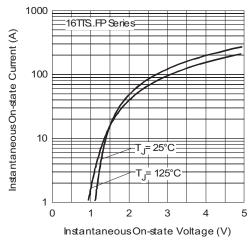
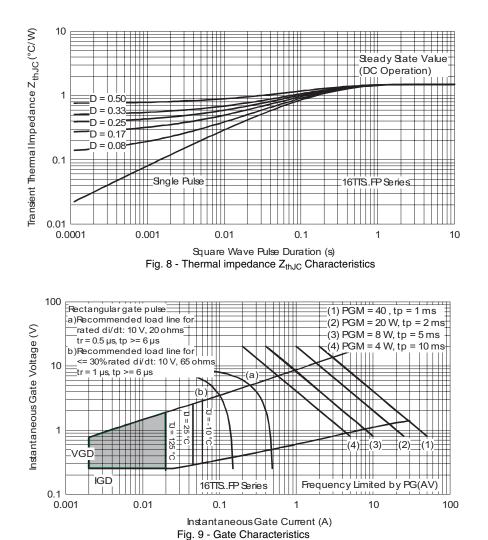


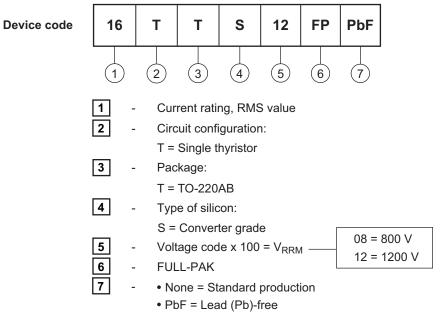
Fig. 7 - On-State Voltage Drop Characteristics



Vishay High Power Products Phase Control SCR TO-220AB FULL-PAK, 16 A



#### ORDERING INFORMATION TABLE



Note: For higher voltage up to 1600 V contact factory

LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95072			
Part marking information	http://www.vishay.com/doc?95069		



Vishay

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